- Low-Voltage and Single-Supply Operation
  V<sub>CC</sub> = 2 V to 7 V
- Common-Mode Voltage Range Includes Ground
- Fast Response Time 450 ns Typ (TLV2393)
- Low Supply Current
  0.16 mA Typ (TLV1393)
- Fully Specified at 3-V and 5-V Supply Voltages

#### 

#### description

The TLV1393 and the TLV2393 are dual differential comparators built using a new Texas Instruments low-voltage, high-speed bipolar process. These devices have been specifically developed for low-voltage, single-supply applications. Their enhanced performance makes them excellent replacements for the LM393 in today's improved 3-V and 5-V system designs.

The TLV1393, with its typical supply current of only 0.16 mA, is ideal for low-power systems. Response time has also been improved to 0.7  $\mu$ s. For higher-speed applications, the TLV2393 features excellent ac performance with a response time of just 0.45  $\mu$ s, three times that of the LM393.

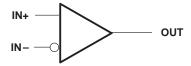
Package availability for these devices includes the TSSOP (thin-shrink small-outline package). With a maximum thickness of 1.1 mm and a package area that is 25% smaller than the standard surface-mount package, the TSSOP is ideal for high-density circuits, particularly in hand-held and portable equipment.

#### **AVAILABLE OPTIONS**

	PACKAGED DEVICES					
TA	SUPPLY CURRENT (TYP)	RESPONSE TIME (TYP)	SMALL OUTLINE (D)	PLASTIC DIP (P)	TSSOP (PW)†	CHIP FORM (Y)
-40°C to 105°C	0.16 mA 1.1 mA	0.7 μs 0.45 μs	TLV1393ID TLV2393ID	TLV1393IP TLV2393IP	TLV1393IPWLE TLV2393IPWLE	TLV1393Y TLV2393Y

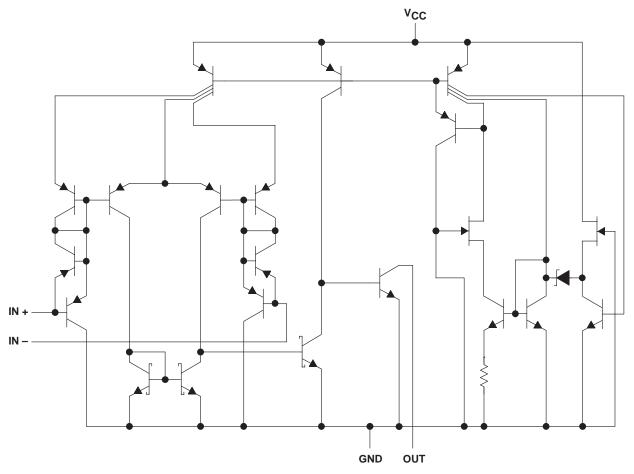
<sup>†</sup> The PW packages are only available left-ended taped and reeled (e.g., TLV1393IPWLE).

#### symbol (each comparator)



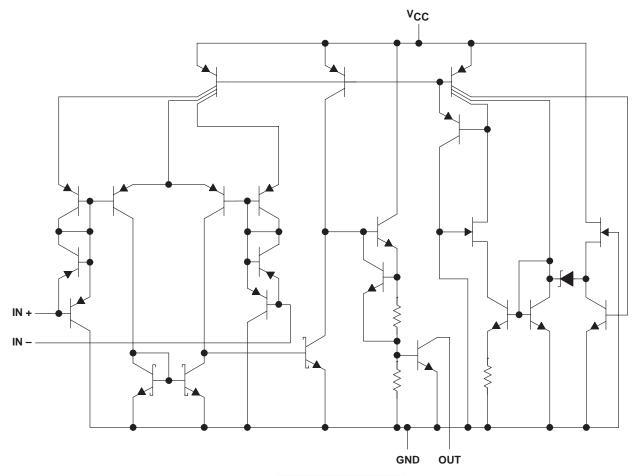


## TLV1393, TLV1393Y equivalent schematic (each comparator)



COMPONENT COUNT					
44					
1					
7					
2					

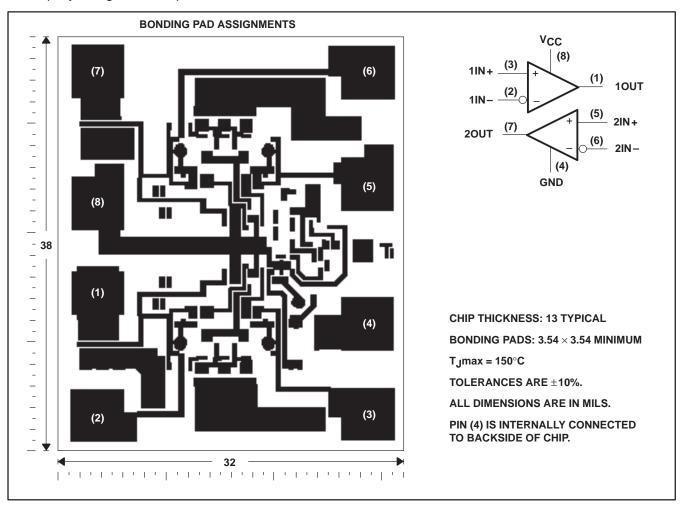
## TLV2393, TLV2393Y equivalent schematic (each comparator)



COMPONENT COUNT					
44					
1					
7					
2					

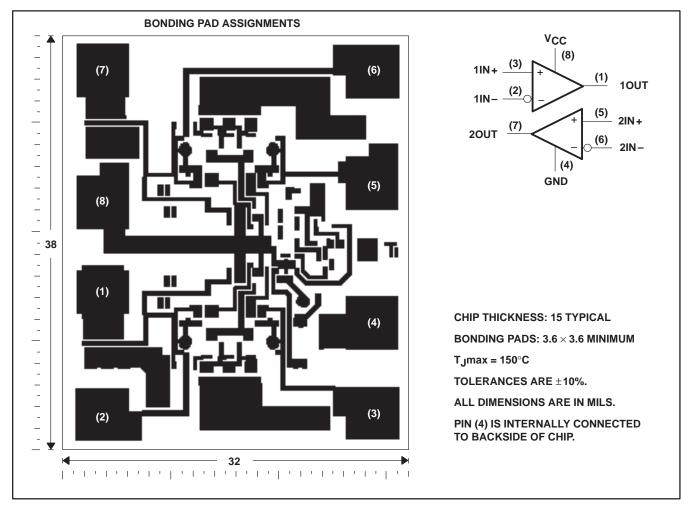
## **TLV1393Y chip information**

This chip, when properly assembled, displays characteristics similar to the TLV1393. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.



### **TLV2393Y** chip information

This chip, when properly assembled, displays characteristics similar to the TLV2393. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.



SLCS121A - AUGUST 1993 - REVISED APRIL 1994

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V <sub>CC</sub> (see Note 1)	7 V
Differential input voltage, V <sub>ID</sub> (see Note 2)	7 V
Input voltage, V <sub>I</sub> (any input)	7 V
Output voltage, V <sub>O</sub>	7 V
Output current, IO (each output)	20 mA
Duration of short-circuit current to GND (see Note 3)	unlimited
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, T <sub>A</sub>	40°C to 105°C
Storage temperature range	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the network GND.
  - 2. Differential voltages are at the noninverting input with respect to the inverting input.
  - 3. Short circuits from the outputs to V<sub>CC</sub> can cause excessive heating and eventual destruction of the chip.

#### **DISSIPATION RATING TABLE**

PACKAGE	$\begin{aligned} & \textbf{T}_{\pmb{A}} \leq \textbf{25}^{\circ}\textbf{C} \\ & \textbf{POWER RATING} \end{aligned}$	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING
D	725 mW	5.8 mW/° C	464 mW	377 mW
Р	1000 mW	8.0 mW/° C	640 mW	520 mW
PW	525 mW	4.2 mW/°C	336 mW	273 mW

### recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, V <sub>CC</sub>	2	7	V
Operating free-air temperature, T <sub>A</sub>	-40	105	°C



## electrical characteristics, $V_{CC} = 3 V$

PARAMETER		TEST CONDITIONS		+	TLV1393			UNIT
	PARAMETER	l lESI C	CNDITIONS	T <sub>A</sub> †	MIN	TYP	MAX	UNII
V10	Input offset voltage	Vo = 1.4.V	Via – Vianmin	25°C		1.5	5	mV
VIO	input onset voltage	VO = 1.4 V,	VIC = VICRmin	Full range		120	9	IIIV
				25°C	0 to	0 to		
VICR	Common-mode input voltage range				V <sub>CC</sub> – 1.5	V <sub>CC</sub> -1.2		V
	, ,			Full range	0 to V <sub>CC</sub> -2			
VOL	Low-level output voltage	$V_{ID} = -1 V$ ,	I <sub>OL</sub> = 500 μA	Full range		120	300	mV
l.o	Input offset surrent	Vo. 4.4.V	25°C		5	50	nA	
lio	Input offset current	V <sub>O</sub> = 1.4 V		Full range			150	IIA
lun.	Input bias current	\/a 1 1 \/	-141/	25°C		-40	-250	nA
lΒ	input bias current	V <sub>O</sub> = 1.4 V		Full range			-400	ПА
1	High-level output current	$V_{ID} = 1 V$	V <sub>OH</sub> = 3 V	25°C		0.1		nA
ЮН	rigii-level output current	V <sub>ID</sub> = 1 V,	V <sub>OH</sub> = 5 V	Full range			100	IIA
loL	Low-level output current	$V_{ID} = -1 V$ ,	V <sub>OL</sub> = 1.5 V	25°C	500			μΑ
	Lligh lovel events everent	\/a \/a		25°C		160	250	
Іссн	High-level supply current	VO = VOH		Full range			300	
lasi	Low lovel cumply current	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\		25°C		160	250	μΑ
ICCL	Low-level supply current	VO = VOL		Full range			300	

<sup>†</sup> Full range is –40°C to 105°C.

## switching characteristics, $V_{CC}$ = 3 V, $C_L$ = 15 pF, $T_A$ = 25°C

PARAMETER	TEST CONDITIONS	Т	UNIT		
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNII
Response time	100-mV input step with 5-mV overdrive, RL connected to 5 V through 5.1 k $\Omega$		0.7		μs

SLCS121A - AUGUST 1993 - REVISED APRIL 1994

## electrical characteristics, $V_{CC} = 5 V$

PARAMETER		TEST CONDITIONS		T. +		UNIT		
	PARAMETER	IESIC	CNDITIONS	T <sub>A</sub> †	MIN	TYP	MAX	UNIT
1/10	Input offset voltage	Vo - 1.4.V	\/.o - \/.opmin	25°C		1.5	5	mV
VIO	input onset voltage	VO = 1.4 V,	VIC = VICRmin	Full range			9	IIIV
				25°C	0 to	0 to		
VICR	Common-mode input voltage range			20 0	V <sub>CC</sub> – 1.5	V <sub>CC</sub> -1.2		V
VICK Common mod	Common mode input voltage range			Full range	0 to V <sub>CC</sub> -2			v
VOL	Low-level output voltage	$V_{ID} = -1 V$ ,	I <sub>OL</sub> = 500 μA	Full range		120	300	mV
1	I <sub>IO</sub> Input offset current V <sub>O</sub> =	V- 14V	25°C		5	50	nA	
I IIO		V <sub>O</sub> = 1.4 V		Full range			150	IIA
1	lanut biog gurrant	V 44V	4.1/	25°C		-40	-250	- A
ΙΒ	Input bias current	V <sub>O</sub> = 1.4 V		Full range			-400	nA
1	High-level output current	$V_{ID} = 1 V$	V <sub>OH</sub> = 3 V	25°C		0.1		nA
ЮН	nigri-iever output current	$V_{ID} = 1 V$ ,	V <sub>OH</sub> = 5 V	Full range			100	IIA
lOL	Low-level output current	$V_{ID} = -1 V$ ,	$V_{OL} = 1.5 \text{ V}$	25°C	600			μΑ
	High level comply correct	V- V		25°C		200	300	
ICCH	High-level supply current	VO = VOH		Full range			350	
la a i	Low lovel cumply current	V- V-		25°C		200	300	μΑ
ICCL	Low-level supply current	VO = VOL		Full range			350	

<sup>†</sup>Full range is -40°C to 105°C.

## switching characteristics, $V_{CC}$ = 5 V, $C_L$ = 15 pF, $T_A$ = 25°C

PARAMETER	TEST CONDITIONS			TLV1393			
PARAMETER	TEST CON	DITIONS	MIN	TYP	MAX	UNIT	
Boonongo timo	100-mV input step with 5-mV overdrive,	R <sub>L</sub> connected to 5 V through 5.1 k $\Omega$		0.65			
Response time	TTL-level input step,	RL connected to 5 V through 5.1 k $\Omega$		0.18		μs	

## electrical characteristics, $V_{CC}$ = 3 V, $T_A$ = 25°C

PARAMETER		TEST	TEST CONDITIONS		TLV1393Y			
	PARAMETER	IESTO	ONDITIONS	MIN	TYP	P MAX UNI		
۷ <sub>IO</sub>	Input offset voltage	$V_0 = 1.4 V$ ,	V <sub>IC</sub> = V <sub>ICR</sub> min		1.5	5	mV	
V <sub>ICR</sub>	Common-mode input voltage range			0 to V <sub>CC</sub> – 1.5	0 to V <sub>CC</sub> -1.2		V	
ΙΙΟ	Input offset current	V <sub>O</sub> = 1.4 V			5	50	nA	
I <sub>IB</sub>	Input bias current	V <sub>O</sub> = 1.4 V			-40	-250	nA	
loh	High-level output current	V <sub>ID</sub> = 1 V,	V <sub>OH</sub> = 3 V		0.1		nA	
loL	Low-level output current	$V_{ID} = -1 V$ ,	V <sub>OL</sub> = 1.5 V	500			μΑ	
ICCH	High-level supply current	Vo = VoH	·		160	250		
ICCL	Low-level supply current	$V_O = V_{OL}$			160	250	μΑ	

## switching characteristics, $V_{CC}$ = 3 V, $C_L$ = 15 pF, $T_A$ = 25°C

PARAMETER	TEST CONDITIONS	TI	UNIT		
PARAWETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Response time	100-mV input step with 5-mV overdrive, RL connected to 5 V through 5.1 k $\Omega$		0.7		μs



SLCS121A - AUGUST 1993 - REVISED APRIL 1994

## electrical characteristics, $V_{\mbox{\footnotesize CC}}$ = 5 V, $T_{\mbox{\footnotesize A}}$ = 25°C

	PARAMETER	TEST	ONDITIONS	Т	LV1393Y		UNIT
	PARAMETER	l lesi c	TEST CONDITIONS		TYP	MAX	UNII
V <sub>IO</sub>	Input offset voltage	$V_0 = 1.4 V$ ,	$V_{IC} = V_{ICR}min$		1.5	5	mV
VICR	Common-mode input voltage range			0 to V <sub>CC</sub> – 1.5	0 to V <sub>CC</sub> -1.2		V
IIO	Input offset current	V <sub>O</sub> = 1.4 V			5	50	nA
I <sub>IB</sub>	Input bias current	V <sub>O</sub> = 1.4 V			-40	-250	nA
ІОН	High-level output current	V <sub>ID</sub> = 1 V,	V <sub>OH</sub> = 3 V		0.1		nA
loL	Low-level output current	$V_{ID} = -1 V$ ,	V <sub>OL</sub> = 1.5 V	600			μΑ
ICCH	High-level supply current	VO = VOH			200	300	
ICCL	Low-level supply current	VO = VOF			200	300	μΑ

## switching characteristics, $V_{CC}$ = 5 V, $C_L$ = 15 pF, $T_A$ = 25°C

PARAMETER	TEST CON	DITIONS	TLV1393Y			UNIT	
PARAMETER	TEST CONDITIONS			TYP	MAX	UNIT	
Response time	100-mV input step with 5-mV overdrive,	nV overdrive, R <sub>L</sub> connected to 5 V through 5.1 k $\Omega$		0.65			
Response time	TTL-level input step,	RL connected to 5 V through 5.1 $k\Omega$		0.18		μs	

SLCS121A - AUGUST 1993 - REVISED APRIL 1994

## electrical characteristics, $V_{CC} = 3 V$

	DADAMETED	TEST C	ONDITIONS	<b>T.</b> †		TLV2393		UNIT
	PARAMETER	IESI C	ONDITIONS	T <sub>A</sub> †	MIN	TYP	MAX	UNII
V10	Input offset voltage	Vo = 1.4.V	V <sub>IC</sub> = V <sub>ICR</sub> min	25°C		1.5	5	mV
VIO	input onset voltage	VO = 1.4 V,	AIC = AICKIIIII	Full range			9	IIIV
				25°C	0 to V <sub>CC</sub> – 1.5	0 to V <sub>CC</sub> -1.2		
VICR	Common-mode input voltage range			Full range	0 to V <sub>CC</sub> -2			V
Vai	Low lovel output voltage	$V_{ID} = -1 V$ ,	I <sub>OL</sub> = 1 mA	25°C		80	300	mV
VOL	Low-level output voltage	$V_{ID} = -1 V$ ,	I <sub>OL</sub> = 4 mA	Full range		250	700	IIIV
li o	Input offset current	V <sub>O</sub> = 1.4 V		25°C		5	50	nA
10	input onset current	VO = 1.4 V		Full range			150	IIA
lin.	Input bias current	V <sub>O</sub> = 1.4 V		25°C		-100	-250	nA
ΙΒ	input bias current			Full range			-400	IIA
lou	High-level output current	V <sub>ID</sub> = 1 V,	V <sub>OH</sub> = 3 V	25°C		0.1		nA
ЮН	nign-level output current	V <sub>ID</sub> = 1 V,	V <sub>OH</sub> = 5 V	Full range			100	IIA
lOL	Low-level output current	$V_{ID} = -1 V$ ,	V <sub>OL</sub> = 1.5 V	25°C	4			mA
	High lavel comply compart	VO = VOH		25°C		450	600	μА
ICCH	High-level supply current			Full range			700	
lage	Low lovel supply surrent	Vo = Vo.	M M			1.1	1.3	mA
ICCL	Low-level supply current	Vo = VoL		Full range			1.4	IIIA

<sup>†</sup> Full range is –40°C to 105°C.

## switching characteristics, $V_{CC}$ = 3 V, $C_L$ = 15 pF, $T_A$ = 25 $^{\circ}C$

PARAMETER	TEST CONDITIONS	Т	LV2393		UNIT
PARAMETER	PARAMETER TEST CONDITIONS				UNIT
Response time	100-mV input step with 5-mV overdrive, RL connected to 5 V through 5.1 k $\Omega$		0.45	1	μs

## electrical characteristics, $V_{CC} = 5 V$

	PARAMETER	TECT	ONDITIONS	- +		TLV2393		UNIT	
	PARAMETER	IESIC	ONDITIONS	T <sub>A</sub> †	MIN	TYP	MAX	UNII	
1/10	Input offset voltage	Vo = 1.4.V	\/.o - \/.o = min	25°C		1.5	5	mV	
VIO	input onset voltage	VO = 1.4 V,	VIC = VICRmin	Full range			9	IIIV	
V <sub>ICR</sub> Common-mode input voltage range				25°C	0 to V <sub>CC</sub> – 1.5	0 to V <sub>CC</sub> -1.2		٧	
		Common-mode input voltage range		Full range	0 to V <sub>CC</sub> –2			V	
Va. Low level output voltage		$V_{ID} = -1 V$ ,	I <sub>OL</sub> = 1 mA	25°C		70	300	mV	
VOL	Low-level output voltage	$V_{ID} = -1 V$ ,	$I_{OL} = 4 \text{ mA}$	Full range		200	700	IIIV	
lea langut offeet gurrent	I <sub>IO</sub> Input offset current V <sub>O</sub> =	V <sub>O</sub> = 1.4 V	\_14\/			5	50	nA	
L'IO		VO = 1.4 V		Full range			150	IIA	
l.a	Input bias current	rent $V_O = 1.4 \text{ V}$		25°C		-100	-250	nA	
IB	input bias current			Full range			-400	nA	
lau	High lovel output ourrent	V <sub>ID</sub> = 1 V,	V <sub>OH</sub> = 3 V	25°C		0.1		nA	
IОН	High-level output current	V <sub>ID</sub> = 1 V,	V <sub>OH</sub> = 5 V	Full range			100	IIA	
loL	Low-level output current	$V_{ID} = -1 V$ ,	V <sub>OL</sub> = 1.5 V	25°C	6			mA	
	Lliab loval avanh, averant	V- V		25°C		550	700		
Іссн	High-level supply current	VO = VOH		Full range			800	μΑ	
lasi	Law law Law along the average			25°C		1.2	1.5	m A	
ICCL	Low-level supply current	VO = VOL		Full range			1.6	mA	

<sup>†</sup> Full range is –40°C to 105°C.

## switching characteristics, $V_{CC}$ = 5 V, $C_L$ = 15 pF, $T_A$ = 25°C

PARAMETER	TEST CON	DITIONS	Т	LV2393		UNIT
PARAMETER	TEST CONDITIONS			TYP	MAX	UNIT
Response time	100-mV input step with 5-mV overdrive,	RL connected to 5 V through 5.1 k $\Omega$		0.4	0.8	
iveshouse time	TTL-level input step,	$R_L$ connected to 5 V through 5.1 $k\Omega$		0.15	0.3	μs

SLCS121A - AUGUST 1993 - REVISED APRIL 1994

## electrical characteristics, $V_{CC}$ = 3 V, $T_A$ = 25°C

	PARAMETER	TEST C	ONDITIONS	Т	LV2393Y		UNIT
	PARAMETER	IESIC	ONDITIONS	MIN	TYP	MAX	UNIT
V <sub>IO</sub>	Input offset voltage	$V_0 = 1.4 V$ ,	$V_{IC} = V_{ICR}min$		1.5	5	mV
VICR	Common-mode input voltage range			0 to V <sub>CC</sub> – 1.5	0 to V <sub>CC</sub> -1.2		V
VOL	Low-level output voltage	$V_{ID} = -1 V$ ,	I <sub>OL</sub> = 1 mA		80	300	mV
lio	Input offset current	V <sub>O</sub> = 1.4 V			5	50	nA
I <sub>IB</sub>	Input bias current	V <sub>O</sub> = 1.4 V			-100	-250	nA
IOH	High-level output current	V <sub>ID</sub> = 1 V,	V <sub>OH</sub> = 3 V		0.1		nA
l <sub>OL</sub>	Low-level output current	$V_{ID} = -1 V$ ,	$V_{OL} = 1.5 \text{ V}$	4			mA
ICCH	High-level supply current	VO = VOH			450	600	μΑ
ICCL	Low-level supply current	VO = VOL			1.1	1.3	mA

## switching characteristics, $V_{CC}$ = 3 V, $C_L$ = 15 pF, $T_A$ = 25°C

PARAMETER	TEST CONDITIONS	TL	V2393Y	'	UNIT
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNII
Response time	100-mV input step with 5-mV overdrive, R <sub>L</sub> connected to 5 V through 5.1 k $\Omega$		0.45	1	μs

## electrical characteristics, $V_{CC}$ = 5 V, $T_A$ = 25°C

	PARAMETER	TEST	ONDITIONS	Т	LV2393Y		UNIT
	PARAMETER	IESIC	ONDITIONS	MIN	TYP	MAX	UNIT
VIO	Input offset voltage	$V_0 = 1.4 V$ ,	V <sub>IC</sub> = V <sub>ICR</sub> min		1.5	5	mV
VICR	Common-mode input voltage range			0 to V <sub>CC</sub> – 1.5	0 to V <sub>CC</sub> -1.2		V
VOL	Low-level output voltage	$V_{ID} = -1 V$ ,	I <sub>OL</sub> = 1 mA		70	300	mV
IIO	Input offset current	V <sub>O</sub> = 1.4 V			5	50	nA
I <sub>IB</sub>	Input bias current	V <sub>O</sub> = 1.4 V			-100	-250	nA
IOH	High-level output current	$V_{ID} = 1 V$ ,	V <sub>OH</sub> = 3 V		0.1		nA
loL	Low-level output current	$V_{ID} = -1 V$ ,	V <sub>OL</sub> = 1.5 V	6			mA
ICCH	High-level supply current	$V_O = V_{OH}$			550	700	μΑ
ICCL	Low-level supply current	VO = VOL			1.2	1.5	mA

## switching characteristics, $V_{CC}$ = 5 V, $C_L$ = 15 pF, $T_A$ = 25°C

PARAMETER	TEST CON	DITIONS	TI	V2393Y	,	UNIT
PARAMETER	TEST CONDITIONS			TYP	MAX	UNIT
Danas tima	100-mV input step with 5-mV overdrive,	R <sub>L</sub> connected to 5 V through 5.1 k $\Omega$		0.4	0.8	
Response time	TTL-level input step,	$R_L$ connected to 5 V through 5.1 $k\Omega$		0.15	0.3	μs

#### TYPICAL CHARACTERISTICS

## **Table of Graphs**

		FIGURE
Input overdrives for TLV1393	vs Low-to-high-level output response time	1, 3
input overdrives for TEV 1393	vs High-to-low-level output response time	2, 4
Input overdrives for TLV2393	vs Low-to-high-level output response time	5, 7
input overdrives for TEV2393	vs High-to-low-level output response time	6, 8

# TLV1393 LOW-TO HIGH-LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES

### Vo - Output Voltage - V 3 40 mV 20 mV 10 mV 5 mV $2\,\text{mV}$ 0 V<sub>ID</sub> – Differential Input Voltage – mV 100 VCC = 3 V0 $T_A = 25^{\circ} C$ 0 0.5 1.5 2 2.5 Low-to High-Level Output Response Time – $\mu$ s

Figure 1

Level Output Response Time – µs

## TLV1393 HIGH-TO LOW-LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES

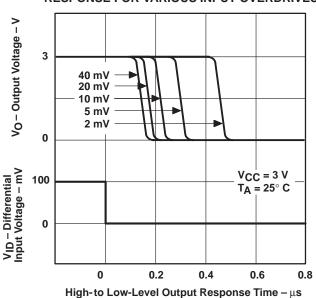
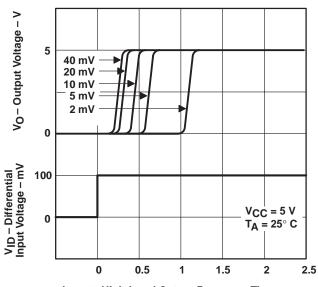


Figure 2

#### TYPICAL CHARACTERISTICS

#### **TLV1393 LOW-TO HIGH-LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES**



Low-to High-Level Output Response Time –  $\mu$ s

Figure 3

#### **TLV2393 LOW-TO HIGH-LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES**

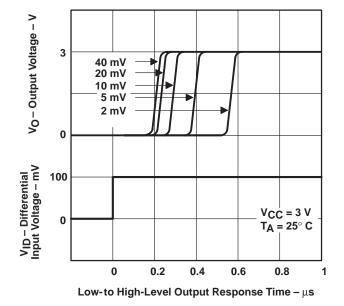


Figure 5

#### **TLV1393 HIGH-TO LOW-LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES**

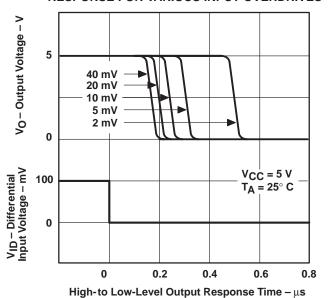


Figure 4

#### TLV2393 HIGH-TO LOW-LEVEL OUTPUT **RESPONSE FOR VARIOUS INPUT OVERDRIVES**

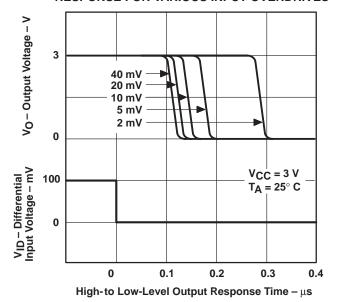


Figure 6

#### TYPICAL CHARACTERISTICS

# TLV2393 LOW-TO HIGH-LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES

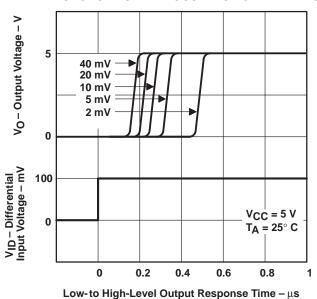


Figure 7

# TLV2393 HIGH-TO LOW-LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES

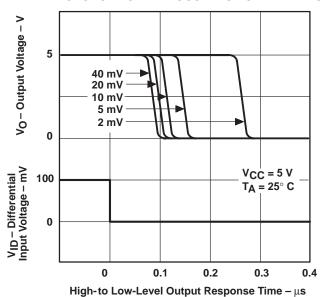


Figure 8





ti.com 30-Mar-2005

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TLV1393CD	OBSOLETE	SOIC	D	8	TBD	Call TI	Call TI
TLV1393ID	OBSOLETE	SOIC	D	8	TBD	Call TI	Call TI
TLV1393IDR	OBSOLETE	SOIC	D	8	TBD	Call TI	Call TI
TLV1393IP	OBSOLETE	PDIP	Р	8	TBD	Call TI	Call TI
TLV1393IPWLE	OBSOLETE	TSSOP	PW	8	TBD	Call TI	Call TI
TLV1393IPWR	OBSOLETE	TSSOP	PW	8	TBD	Call TI	Call TI
TLV2393ID	OBSOLETE	SOIC	D	8	TBD	Call TI	Call TI
TLV2393IDR	OBSOLETE	SOIC	D	8	TBD	Call TI	Call TI
TLV2393IP	OBSOLETE	PDIP	Р	8	TBD	Call TI	Call TI
TLV2393IPWLE	OBSOLETE	TSSOP	PW	8	TBD	Call TI	Call TI
TLV2393IPWR	OBSOLETE	TSSOP	PW	8	TBD	Call TI	Call TI

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

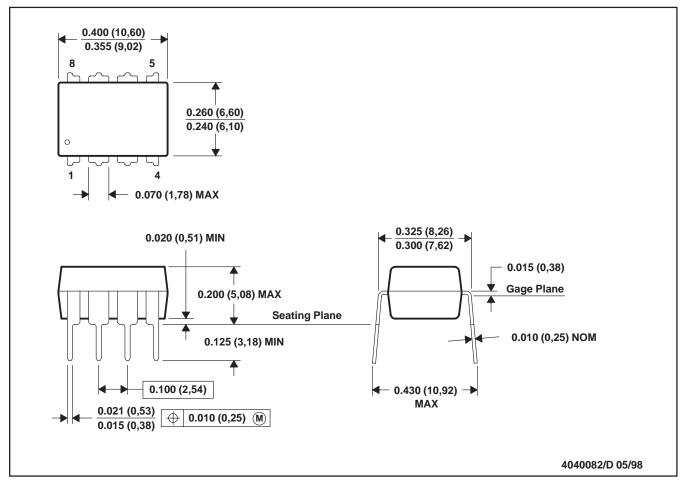
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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### P (R-PDIP-T8)

#### PLASTIC DUAL-IN-LINE



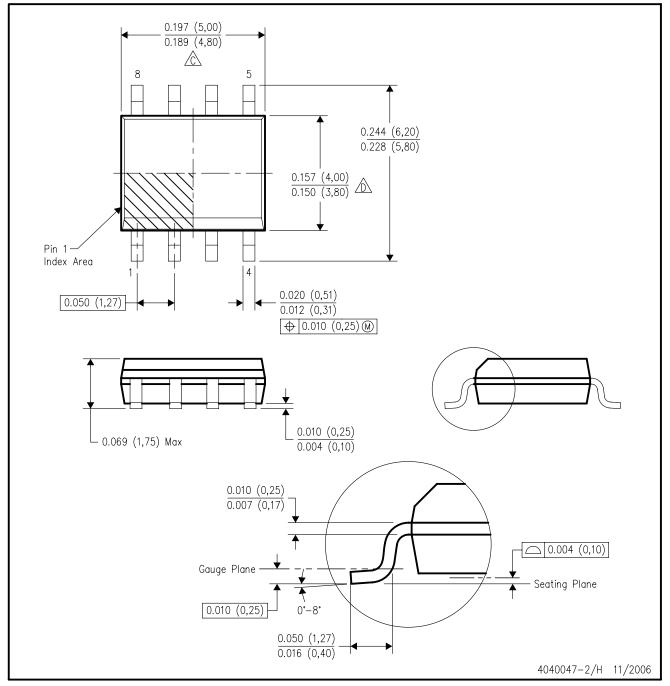
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001

For the latest package information, go to  $http://www.ti.com/sc/docs/package/pkg\_info.htm$ 

## D (R-PDSO-G8)

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AA.



## PW (R-PDSO-G\*\*)

#### 14 PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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